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Applications of "<u>Embedded - Microcontrollers</u>"

Details	
Product Status	Active
Core Processor	PIC
Core Size	8-Bit
Speed	20MHz
Connectivity	-
Peripherals	POR, WDT
Number of I/O	20
Program Memory Size	3KB (2K x 12)
Program Memory Type	OTP
EEPROM Size	-
RAM Size	72 x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 5.5V
Data Converters	-
Oscillator Type	External
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	28-SOIC (0.295", 7.50mm Width)
Supplier Device Package	28-SOIC
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/pic16c57c-20-so

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### PIC16C5X

NOTES:

# 6.5.1 PAGING CONSIDERATIONS – PIC16C56/CR56, PIC16C57/CR57 AND PIC16C58/CR58

If the Program Counter is pointing to the last address of a selected memory page, when it increments it will cause the program to continue in the next higher page. However, the page preselect bits in the STATUS Register will not be updated. Therefore, the next GOTO, CALL or modify PCL instruction will send the program to the page specified by the page preselect bits (PAO or PA<1:0>).

For example, a NOP at location 1FFh (page 0) increments the PC to 200h (page 1). A GOTO xxx at 200h will return the program to address xxh on page 0 (assuming that PA<1:0> are clear).

To prevent this, the page preselect bits must be updated under program control.

#### 6.5.2 EFFECTS OF RESET

The Program Counter is set upon a RESET, which means that the PC addresses the last location in the last page (i.e., the RESET vector).

The STATUS Register page preselect bits are cleared upon a RESET, which means that page 0 is preselected.

Therefore, upon a RESET, a GOTO instruction at the RESET vector location will automatically cause the program to jump to page 0.

#### 6.6 Stack

PIC16C5X devices have a 10-bit or 11-bit wide, two-level hardware push/pop stack.

A CALL instruction will push the current value of stack 1 into stack 2 and then push the current program counter value, incremented by one, into stack level 1. If more than two sequential CALL's are executed, only the most recent two return addresses are stored.

A RETLW instruction will pop the contents of stack level 1 into the program counter and then copy stack level 2 contents into level 1. If more than two sequential RETLW's are executed, the stack will be filled with the address previously stored in level 2. Note that the W Register will be loaded with the literal value specified in the instruction. This is particularly useful for the implementation of data look-up tables within the program memory.

For the RETLW instruction, the PC is loaded with the Top of Stack (TOS) contents. All of the devices covered in this data sheet have a two-level stack. The stack has the same bit width as the device PC, therefore, paging is not an issue when returning from a subroutine.

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## 8.0 TIMERO MODULE AND TMRO REGISTER

The Timer0 module has the following features:

- 8-bit timer/counter register, TMR0
  - Readable and writable
- 8-bit software programmable prescaler
- · Internal or external clock select
  - Edge select for external clock

Figure 8-1 is a simplified block diagram of the Timer0 module, while Figure 8-2 shows the electrical structure of the Timer0 input.

Timer mode is selected by clearing the TOCS bit (OPTION<5>). In Timer mode, the Timer0 module will increment every instruction cycle (without prescaler). If TMR0 register is written, the increment is inhibited for the following two cycles (Figure 8-3 and Figure 8-4). The user can work around this by writing an adjusted value to the TMR0 register.

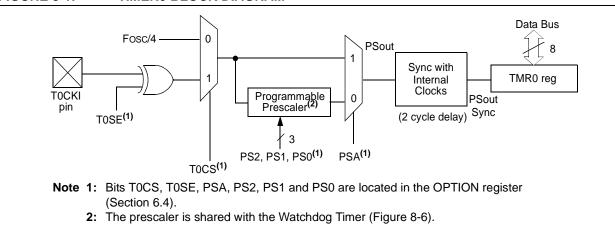
Counter mode is selected by setting the T0CS bit (OPTION<5>). In this mode, Timer0 will increment either on every rising or falling edge of pin T0CKI. The incrementing edge is determined by the source edge select bit T0SE (OPTION<4>). Clearing the T0SE bit selects the rising edge. Restrictions on the external clock input are discussed in detail in Section 8.1.

Note: The prescaler may be used by either the Timer0 module or the Watchdog Timer, but not both.

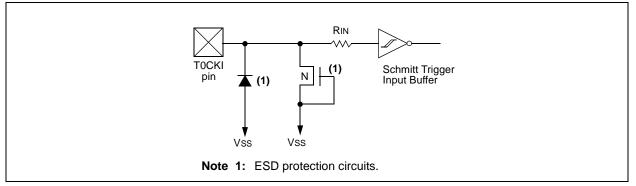
The prescaler assignment is controlled in software by the control bit PSA (OPTION<3>). Clearing the PSA bit will assign the prescaler to Timer0. The prescaler is not readable or writable. When the prescaler is assigned to the Timer0 module, prescale values of 1:2, 1:4,..., 1:256 are selectable. Section 8.2 details the operation of the prescaler.

A summary of registers associated with the Timer0 module is found in Table 8-1.

#### FIGURE 8-1: TIMERO BLOCK DIAGRAM



#### FIGURE 8-2: ELECTRICAL STRUCTURE OF TOCKI PIN



SUBWF	Subtract W from f	SWAPF	Swap Nibbles in f
Syntax:	[ <i>label</i> ] SUBWF f,d	Syntax:	[label] SWAPF f,d
Operands:	$0 \le f \le 31$ $d \in [0,1]$	Operands:	$0 \le f \le 31$ $d \in [0,1]$
Operation: Status Affected:	$(f) - (W) \rightarrow (dest)$ C, DC, Z	Operation:	$(f<3:0>) \rightarrow (dest<7:4>);$ $(f<7:4>) \rightarrow (dest<3:0>)$
		Status Affected:	None
Encoding:	0000 10df ffff	Encoding:	0011 10df ffff
Description:	Subtract (2's complement method) the W register from register 'f'. If 'd' is 0 the result is stored in the W register. If 'd' is 1 the result is stored back in register 'f'.	Description:	The upper and lower nibbles of register 'f' are exchanged. If 'd' is 0 the result is placed in W register. If 'd' is 1 the result is placed in
Words:	1		register 'f'.
Cycles:	1	Words:	1
Example 1:	SUBWF REG1, 1	Cycles:	1
Before Instru	uction	Example	SWAPF REG1, 0
REG1 W C After Instruc REG1	= 3 = 2 = ? ition = 1	Before Instr REG1 After Instruc REG1 W	= 0xA5
W	= 2		
C Evernle 2:	= 1 ; result is positive		
Example 2: Before Instru	uction	TRIS	Load TRIS Register
REG1	= 2	Syntax:	[label] TRIS f
W	= 2	Operands:	f = 5, 6 or 7
С	= ?	Operation:	$(W) \rightarrow TRIS$ register f
After Instruc		Status Affected:	• ,
REG1	= 0		
W	= 2	Encoding:	0000 0000 Offf
C Example 3: Before Ins		Description:	TRIS register 'f' (f = 5, 6, or 7) is loaded with the contents of the W register.
REG1	= 1	Words:	1
W	= 2	Cycles:	1
C	= ?	•	
After Instruc REG1	· ·	Example	TRIS PORTB
W	= 0xFF = 2	Before Instru	
C	= 0 ; result is negative	W After Instruc TRISB	= 0xA5 tion = 0xA5

#### 11.8 MPLAB ICD In-Circuit Debugger

Microchip's In-Circuit Debugger, MPLAB ICD, is a powerful, low cost, run-time development tool. This tool is based on the FLASH PIC MCUs and can be used to develop for this and other PIC microcontrollers. The MPLAB ICD utilizes the in-circuit debugging capability built into the FLASH devices. This feature, along with Microchip's In-Circuit Serial Programming™ protocol, offers cost-effective in-circuit FLASH debugging from the graphical user interface of the MPLAB Integrated Development Environment. This enables a designer to develop and debug source code by watching variables, single-stepping and setting break points. Running at full speed enables testing hardware in real-time.

#### 11.9 PRO MATE II Universal Device Programmer

The PRO MATE II universal device programmer is a full-featured programmer, capable of operating in Stand-alone mode, as well as PC-hosted mode. The PRO MATE II device programmer is CE compliant.

The PRO MATE II device programmer has programmable VDD and VPP supplies, which allow it to verify programmed memory at VDD min and VDD max for maximum reliability. It has an LCD display for instructions and error messages, keys to enter commands and a modular detachable socket assembly to support various package types. In Stand-alone mode, the PRO MATE II device programmer can read, verify, or program PIC devices. It can also set code protection in this mode.

### 11.10 PICSTART Plus Entry Level Development Programmer

The PICSTART Plus development programmer is an easy-to-use, low cost, prototype programmer. It connects to the PC via a COM (RS-232) port. MPLAB Integrated Development Environment software makes using the programmer simple and efficient.

The PICSTART Plus development programmer supports all PIC devices with up to 40 pins. Larger pin count devices, such as the PIC16C92X and PIC17C76X, may be supported with an adapter socket. The PICSTART Plus development programmer is CE compliant.

### 11.11 PICDEM 1 Low Cost PIC MCU Demonstration Board

The PICDEM 1 demonstration board is a simple board which demonstrates the capabilities of several of Microchip's microcontrollers. The microcontrollers supported are: PIC16C5X (PIC16C54 to PIC16C58A). PIC16C61, PIC16C62X, PIC16C71, PIC16C8X, PIC17C42, PIC17C43 and PIC17C44. All necessary hardware and software is included to run basic demo programs. The user can program the sample microcontrollers provided with the PICDEM 1 demonstration board on a PRO MATE II device programmer, or a PICSTART Plus development programmer, and easily test firmware. The user can also connect the PICDEM 1 demonstration board to the MPLAB ICE incircuit emulator and download the firmware to the emulator for testing. A prototype area is available for the user to build some additional hardware and connect it to the microcontroller socket(s). Some of the features include an RS-232 interface, a potentiometer for simulated analog input, push button switches and eight LEDs connected to PORTB.

### 11.12 PICDEM 2 Low Cost PIC16CXX Demonstration Board

The PICDEM 2 demonstration board is a simple demonstration board that supports the PIC16C62, PIC16C64, PIC16C65, PIC16C73 and PIC16C74 microcontrollers. All the necessary hardware and software is included to run the basic demonstration programs. The user can program the sample microcontrollers provided with the PICDEM 2 demonstration board on a PRO MATE II device programmer, or a PICSTART Plus development programmer, and easily test firmware. The MPLAB ICE in-circuit emulator may also be used with the PICDEM 2 demonstration board to test firmware. A prototype area has been provided to the user for adding additional hardware and connecting it to the microcontroller socket(s). Some of the features include a RS-232 interface, push button switches, a potentiometer for simulated analog input, a serial EEPROM to demonstrate usage of the I<sup>2</sup>C<sup>TM</sup> bus and separate headers for connection to an LCD module and a keypad.

#### 12.1 DC Characteristics: PIC16C54/55/56/57-RC, XT, 10, HS, LP (Commercial)

PIC16C54/55/56/57-RC, XT, 10, HS, LP (Commercial)		Standard Operating Conditions (unless otherwise specified Operating Temperature $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial					
Param No.	Symbol	Characteristic/Device	Min	Тур†	Max	Units	Conditions
D001	VDD	Supply Voltage PIC16C5X-RC PIC16C5X-XT PIC16C5X-10 PIC16C5X-HS PIC16C5X-LP	3.0 3.0 4.5 4.5 2.5		6.25 6.25 5.5 5.5 6.25	V V V	
D002	Vdr	RAM Data Retention Voltage <sup>(1)</sup>		1.5*	_	V	Device in SLEEP Mode
D003	VPOR	VDD Start Voltage to ensure Power-on Reset		Vss	_	V	See Section 5.1 for details on Power-on Reset
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	_	_	V/ms	See Section 5.1 for details on Power-on Reset
D010	IDD	Supply Current <sup>(2)</sup> PIC16C5X-RC <sup>(3)</sup> PIC16C5X-XT PIC16C5X-10 PIC16C5X-HS PIC16C5X-HS PIC16C5X-LP		1.8 1.8 4.8 4.8 9.0	3.3 3.3 10 10 20 32	mA mA mA mA mA	FOSC = 4 MHz, VDD = 5.5V FOSC = 4 MHz, VDD = 5.5V FOSC = 10 MHz, VDD = 5.5V FOSC = 10 MHz, VDD = 5.5V FOSC = 20 MHz, VDD = 5.5V FOSC = 32 kHz, VDD = 3.0V, WDT disabled
D020	IPD	Power-down Current <sup>(2)</sup>	_	4.0 0.6	12 9	μA μA	VDD = 3.0V, WDT enabled VDD = 3.0V, WDT disabled

<sup>\*</sup> These parameters are characterized but not tested.

- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
  - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
    - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, TOCKI = VDD,  $\overline{MCLR} = VDD$ ; WDT enabled/disabled as specified.
    - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
  - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in  $k\Omega$ .

<sup>†</sup> Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

#### 13.2 DC Characteristics: PIC16CR54A-04E, 10E, 20E (Extended)

PIC16CR54A-04E, 10E, 20E (Extended)				Standard Operating Conditions (unless otherwise specified) Operating Temperature −40°C ≤ TA ≤ +125°C for extended				
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
D001	VDD	Supply Voltage RC, XT and LP modes HS mode	3.25 4.5	_	6.0 5.5	> >		
D002	Vdr	RAM Data Retention Voltage <sup>(1)</sup>	_	1.5*	_	V	Device in SLEEP mode	
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	_	Vss	_	V	See Section 5.1 for details on Power-on Reset	
D004	SVDD	VDD Rise Rate to ensure Power- on Reset	0.05*	_	_	V/ms	See Section 5.1 for details on Power-on Reset	
D010	IDD	Supply Current <sup>(2)</sup> RC <sup>(3)</sup> and XT modes HS mode HS mode		1.8 4.8 9.0	3.3 10 20	mA mA mA	Fosc = 4.0 MHz, VDD = 5.5V Fosc = 10 MHz, VDD = 5.5V Fosc = 16 MHz, VDD = 5.5V	
D020	IPD	Power-down Current <sup>(2)</sup>	_	5.0 0.8	22 18	μ <b>Α</b> μ <b>Α</b>	VDD = 3.25V, WDT enabled VDD = 3.25V, WDT disabled	

These parameters are characterized but not tested.

- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
  - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
    - a) The test conditions for all IDD measurements in active Operation mode are: OSC1 = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
    - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
  - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in kΩ.

<sup>†</sup> Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

#### 13.4 DC Characteristics: PIC16CR54A-04E, 10E, 20E (Extended)

DC CHARACTERISTICS			Standard Operating Conditions (unless otherwise specified) Operating Temperature $-40^{\circ}\text{C} \le \text{TA} \le +125^{\circ}\text{C}$ for extended					
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions	
D030	VIL	Input Low Voltage I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1	Vss Vss Vss Vss Vss		0.15 VDD 0.15 VDD 0.15 VDD 0.15 VDD 0.3 VDD	> > > > > > > > > > > > > > > > > > >	Pin at hi-impedance  RC mode only <sup>(3)</sup> XT, HS and LP modes	
D040	VIH	Input High Voltage I/O ports I/O ports I/O ports I/O ports MCLR (Schmitt Trigger) T0CKI (Schmitt Trigger) OSC1 (Schmitt Trigger) OSC1 Hysteresis of Schmitt Trigger inputs	0.45 VDD 2.0 0.36 VDD 0.85 VDD 0.85 VDD 0.85 VDD 0.7 VDD		VDD VDD VDD VDD VDD VDD VDD	V V V V V	For all $VDD^{(4)}$ $4.0V < VDD \le 5.5V^{(4)}$ VDD > 5.5V RC mode only <sup>(3)</sup> XT, HS and LP modes	
D060	lıL	Input Leakage Current <sup>(1,2)</sup> I/O ports  MCLR MCLR TOCKI OSC1	-1.0 -5.0  -3.0 -3.0	0.5 — 0.5 0.5 0.5	+1.0  +5.0 +3.0 +3.0	μΑ μΑ μΑ μΑ μΑ	For VDD ≤ 5.5V:  VSS ≤ VPIN ≤ VDD, pin at hi-impedance  VPIN = VSS + 0.25V  VPIN = VDD  VSS ≤ VPIN ≤ VDD  VSS ≤ VPIN ≤ VDD, XT, HS and LP modes	
D080	Vol	Output Low Voltage I/O ports OSC2/CLKOUT		_ _	0.6 0.6	V V	IOL = 8.7 mA, VDD = 4.5V IOL = 1.6 mA, VDD = 4.5V, RC mode only	
D090	Voн	Output High Voltage <sup>(2)</sup> I/O ports OSC2/CLKOUT	VDD - 0.7 VDD - 0.7	_ _		V V	IOH = -5.4 mA, VDD = 4.5V IOH = -1.0 mA, VDD = 4.5V, RC mode only	

<sup>\*</sup> These parameters are characterized but not tested.

- 2: Negative current is defined as coming out of the pin.
- **3:** For the RC mode, the OSC1/CLKIN pin is a Schmitt Trigger input. It is not recommended that the PIC16C5X be driven with external clock in RC mode.
- 4: The user may use the better of the two specifications.

<sup>†</sup> Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.

**Note 1:** The leakage current on the MCLR/VPP pin is strongly dependent on the applied voltage level. The specified levels represent normal operating conditions. Higher leakage current may be measured at different input voltage.

#### FIGURE 13-5: TIMERO CLOCK TIMINGS - PIC16CR54A

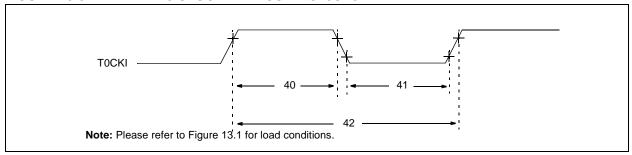


TABLE 13-4: TIMERO CLOCK REQUIREMENTS - PIC16CR54A

	AC Chara	acteristics	Conditions (unless ure $0^{\circ}C \le$ $-40^{\circ}C \le$ $-40^{\circ}C \le$	$TA \le +7$ $TA \le +8$	70°C fo 35°C fo	or comn or indus	nercial etrial	
Param No.	Symbol	C	Characteristic	Min	Тур†	Max	Units	Conditions
40	Tt0H	T0CKI High I	Pulse Width					
			<ul> <li>No Prescaler</li> </ul>	0.5 Tcy + 20*	_	_	ns	
			<ul> <li>With Prescaler</li> </ul>	10*		_	ns	
41	Tt0L	T0CKI Low F	Pulse Width					
			<ul> <li>No Prescaler</li> </ul>	0.5 Tcy + 20*	_	_	ns	
			- With Prescaler	10*		_	ns	
42	Tt0P	T0CKI Period	t	20 or <u>Tcy + 40</u> *	_	_	ns	Whichever is greater.

<sup>\*</sup> These parameters are characterized but not tested.

Ν

N = Prescale Value

(1, 2, 4,..., 256)

<sup>†</sup> Data in the Typical ("Typ") column is at 5.0V, 25°C unless otherwise stated. These parameters are for design guidance only and are not tested.

15.1 DC Characteristics: PIC16C54A-04, 10, 20 (Commercial)
PIC16C54A-04I, 10I, 20I (Industrial)
PIC16LC54A-04 (Commercial)
PIC16LC54A-04I (Industrial)

PIC16LC54A-04 PIC16LC54A-04I (Commercial, Industrial)				ard Ope ting Tem	-	ire	tions (unless otherwise specified) $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $40^{\circ}C \le TA \le +85^{\circ}C$ for industrial
PIC16C54A-04, 10, 20 PIC16C54A-04I, 10I, 20I (Commercial, Industrial)					_	ire	tions (unless otherwise specified) $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $40^{\circ}C \le TA \le +85^{\circ}C$ for industrial
Param No.	Symbol	Characteristic/Device	Min Typ† Max Units Conditions				Conditions
	IPD	Power-down Current <sup>(2)</sup>					
D006		PIC16LC5X		2.5 0.25 2.5 0.25	12 4.0 14 5.0	μΑ μΑ μΑ μΑ	VDD = 2.5V, WDT enabled, Commercial VDD = 2.5V, WDT disabled, Commercial VDD = 2.5V, WDT enabled, Industrial VDD = 2.5V, WDT disabled, Industrial
D006A		PIC16C5X	1111	4.0 0.25 5.0 0.3	12 4.0 14 5.0	μΑ μΑ μΑ μΑ	VDD = 3.0V, WDT enabled, Commercial VDD = 3.0V, WDT disabled, Commercial VDD = 3.0V, WDT enabled, Industrial VDD = 3.0V, WDT disabled, Industrial

Legend: Rows with standard voltage device data only are shaded for improved readability.

- \* These parameters are characterized but not tested.
- † Data in "Typ" column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
  - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
    - a) The test conditions for all IDD measurements in active Operation mode <u>are: OSC1</u> = external square wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/disabled as specified.
    - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
  - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in  $k\Omega$ .

### 15.3 DC Characteristics: PIC16LV54A-02 (Commercial) PIC16LV54A-02I (Industrial)

PIC16LV54A-02 PIC16LV54A-02I (Commercial, Industrial)				ard Ope		ure	itions (unless otherwise specified) $0^{\circ}C \le TA \le +70^{\circ}C$ for commercial $-20^{\circ}C \le TA \le +85^{\circ}C$ for industrial
Param No.	Symbol	Characteristic	Min	Тур†	Max	Units	Conditions
D001	VDD	Supply Voltage RC and XT modes	2.0	_	3.8	V	
D002	VDR	RAM Data Retention Voltage <sup>(1)</sup>	_	1.5*	_	V	Device in SLEEP mode
D003	VPOR	VDD Start Voltage to ensure Power-on Reset	_	Vss	_	V	See Section 5.1 for details on Power-on Reset
D004	SVDD	VDD Rise Rate to ensure Power-on Reset	0.05*	_	_	V/ms	See Section 5.1 for details on Power-on Reset
D010	IDD	Supply Current <sup>(2)</sup> RC <sup>(3)</sup> and XT modes LP mode, Commercial LP mode, Industrial		0.5 11 14	 27 35	mA μA μA	Fosc = 2.0 MHz, VDD = 3.0V Fosc = 32 kHz, VDD = 2.5V WDT disabled Fosc = 32 kHz, VDD = 2.5V WDT disabled
D020	IPD	Power-down Current <sup>(2,4)</sup> Commercial Commercial Industrial	_ _ _	2.5 0.25 3.5	12 4.0 14	μΑ μΑ μΑ	VDD = 2.5V, WDT enabled VDD = 2.5V, WDT disabled VDD = 2.5V, WDT enabled
		Industrial		0.3	5.0	μA	VDD = 2.5V, WDT disabled

<sup>\*</sup> These parameters are characterized but not tested.

- † Data in the Typical ("Typ") column is based on characterization results at 25°C. This data is for design guidance only and is not tested.
- Note 1: This is the limit to which VDD can be lowered in SLEEP mode without losing RAM data.
  - 2: The supply current is mainly a function of the operating voltage and frequency. Other factors such as bus loading, oscillator type, bus rate, internal code execution pattern and temperature also have an impact on the current consumption.
    - a) The test conditions for all IDD measurements in active Operation mode <u>are: OSC1 = external square</u> wave, from rail-to-rail; all I/O pins tristated, pulled to Vss, T0CKI = VDD, MCLR = VDD; WDT enabled/ disabled as specified.
    - b) For standby current measurements, the conditions are the same, except that the device is in SLEEP mode. The power-down current in SLEEP mode does not depend on the oscillator type.
  - 3: Does not include current through REXT. The current through the resistor can be estimated by the formula: IR = VDD/2REXT (mA) with REXT in  $k\Omega$ .
  - **4:** The oscillator start-up time can be as much as 8 seconds for XT and LP oscillator selection on wake-up from SLEEP mode or during initial power-up.

FIGURE 16-18: TRANSCONDUCTANCE (gm) OF LP OSCILLATOR vs. VDD

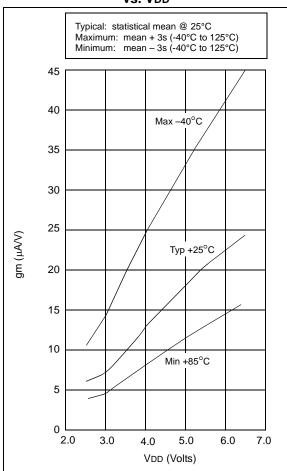
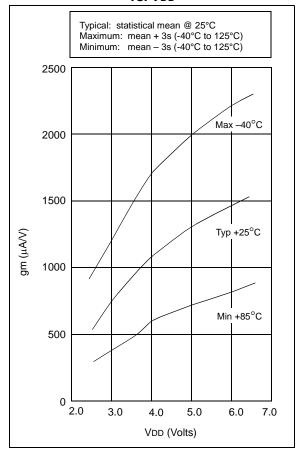


FIGURE 16-19: TRANSCONDUCTANCE (gm) OF XT OSCILLATOR vs. VDD



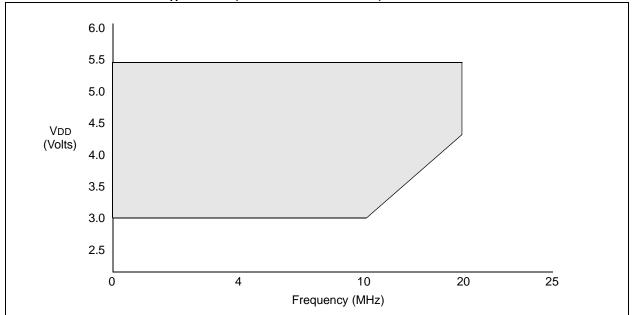
#### 17.0 ELECTRICAL CHARACTERISTICS - PIC16LC54A

#### Absolute Maximum Ratings(†)

Ambient temperature under bias	55°C to +125°C
Storage temperature	–65°C to +150°C
Voltage on VDD with respect to Vss	
Voltage on MCLR with respect to Vss	0 to +14V
Voltage on all other pins with respect to Vss	0.6V to (VDD + 0.6V)
Total power dissipation <sup>(1)</sup>	
Max. current out of Vss pin	
Max. current into VDD pin	100 mA
Max. current into an input pin (T0CKI only)	±500 μA
Input clamp current, Iik (Vi < 0 or Vi > VDD)	±20 mA
Output clamp current, loκ (Vo < 0 or Vo > VDD)	±20 mA
Max. output current sunk by any I/O pin	25 mA
Max. output current sourced by any I/O pin	20 mA
Max. output current sourced by a single I/O (Port A, B or C)	50 mA
Max. output current sunk by a single I/O (Port A, B or C)	50 mA
<b>Note 1:</b> Power dissipation is calculated as follows: Pdis = VDD x {IDD - $\Sigma$ IOH} + $\Sigma$ {(VDD-V	$^{\prime}$ OH) x IOH} + $\Sigma$ (VOL x IOL)

† NOTICE: Stresses above those listed under "Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

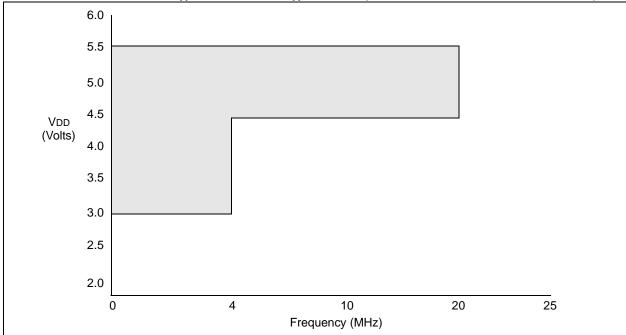
FIGURE 17-1: PIC16C54C/55A/56A/57C/58B-04, 20 VOLTAGE-FREQUENCY GRAPH,  $0^{\circ}C \le T_{A} \le +70^{\circ}C$  (COMMERCIAL TEMPS)



**Note 1:** The shaded region indicates the permissible combinations of voltage and frequency.

2: The maximum rated speed of the part limits the permissible combinations of voltage and frequency. Please reference the Product Identification System section for the maximum rated speed of the parts.

FIGURE 17-2: PIC16C54C/55A/56A/57C/58B-04, 20 VOLTAGE-FREQUENCY GRAPH,  $-40^{\circ}C \leq T_A < 0^{\circ}C, +70^{\circ}C < T_A \leq +125^{\circ}C \text{ (OUTSIDE OF COMMERCIAL TEMPS)}$ 



Note 1: The shaded region indicates the permissible combinations of voltage and frequency.

2: The maximum rated speed of the part limits the permissible combinations of voltage and frequency. Please reference the Product Identification System section for the maximum rated speed of the parts.

### 19.3 Timing Parameter Symbology and Load Conditions

The timing parameter symbols have been created with one of the following formats:

- 1. TppS2ppS
- 2. TppS

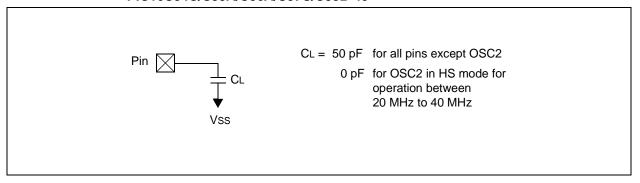
T	
F Frequency	T Time
Lowercase letters (pp) and their meanings:	
рр	
2 45	ma MOLD

pp		
2	to	mc MCLR
ck	CLKOUT	osc oscillator
су	cycle time	os OSC1
drt	device reset timer	t0 T0CKI
io	I/O port	wdt watchdog timer

Uppercase letters and their meanings:

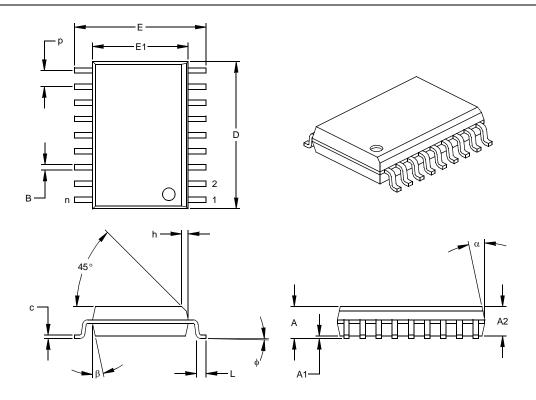
	opportudo lottoro ana tron moaningo.						
S							
F	Fall	Р	Period				
Н	High	R	Rise				
I	Invalid (Hi-impedance)	V	Valid				
L	Low	Z	Hi-impedance				

### FIGURE 19-2: LOAD CONDITIONS FOR DEVICE TIMING SPECIFICATIONS - PIC16C54C/C55A/C56A/C57C/C58B-40



#### 18-Lead Plastic Small Outline (SO) - Wide, 300 mil (SOIC)

For the most current package drawings, please see the Microchip Packaging Specification located Note: at http://www.microchip.com/packaging



	Units	INCHES*			MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n		18			18	
Pitch	р		.050			1.27	
Overall Height	Α	.093	.099	.104	2.36	2.50	2.64
Molded Package Thickness	A2	.088	.091	.094	2.24	2.31	2.39
Standoff §	A1	.004	.008	.012	0.10	0.20	0.30
Overall Width	Е	.394	.407	.420	10.01	10.34	10.67
Molded Package Width	E1	.291	.295	.299	7.39	7.49	7.59
Overall Length	D	.446	.454	.462	11.33	11.53	11.73
Chamfer Distance	h	.010	.020	.029	0.25	0.50	0.74
Foot Length	L	.016	.033	.050	0.41	0.84	1.27
Foot Angle	ф	0	4	8	0	4	8
Lead Thickness	С	.009	.011	.012	0.23	0.27	0.30
Lead Width	В	.014	.017	.020	0.36	0.42	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

.010" (0.254mm) per side. JEDEC Equivalent: MS-013 Drawing No. C04-051

<sup>\*</sup> Controlling Parameter § Significant Characteristic

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